

# Nch 600V 20A Power MOSFET

V <sub>DSS</sub>	600V
R <sub>DS(on)</sub> (Max.)	0.25Ω
Ι <sub>D</sub>	±20A
P <sub>D</sub>	304W

# Features

- 1) Low on-resistance.
- 2) Fast switching speed.
- 3) Gate-source voltage (V\_{GSS}) guaranteed to

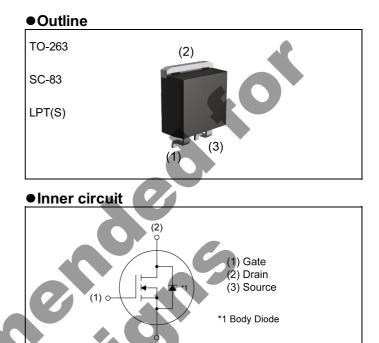
be ±30V.

Application

- 4) Drive circuits can be simple.
- 5) Parallel use is easy.

Switching Power Supply

6) Pb-free plating ; RoHS compliant



# Packaging specifications

Ø	Packing	Embossed Tape
	Reel size (mm)	330
Туре	Tape width (mm)	24
	Basic ordering unit (pcs)	1000
	Taping code	TL
	Marking	R6020ANJ

• Absolute maximum ratings (T<sub>a</sub> = 25°C ,unless otherwise specified)

Parameter	Symbol	Value	Unit
Drain - Source voltage	V <sub>DSS</sub>	600	V
Continuous drain current ( $T_c = 25^{\circ}C$ )	I <sub>D</sub> *1	±20	Α
Pulsed drain current	I <sub>DP</sub> *2	±80	А
Gate - Source voltage	V <sub>GSS</sub>	±30	V
Avalanche current, single pulse	I <sub>AS</sub> *3	10	А
Avalanche energy, single pulse	E <sub>AS</sub> *3	26.7	mJ
Power dissipation $(T_c = 25^{\circ}C)$	P <sub>D</sub>	304	W
Junction temperature	Tj	150	C°
Operating junction and storage temperature range	T <sub>stg</sub>	-55 to +150	C°

### Thermal resistance

Deremeter	Cumph of	Values			l loit
Parameter	Symbol	Min.	Тур.	Max.	Unit
Thermal resistance, junction - case	R <sub>thJC</sub>	-	-	0.41	°C/W
Thermal resistance, junction - ambient	R <sub>thJA</sub>	-	-	80	°C/W
Soldering temperature, wavesoldering for 10s	T <sub>sold</sub>	-		265	°C

# •Electrical characteristics (T<sub>a</sub> = 25°C)

$\begin{array}{c c c c c c c c c c c c c c c c c c c $	-	-						
ParameterSymbolConditionsImageUnitMin.Typ.Max.Drain - Source breakdown voltage $V_{(BR)DSS}$ $V_{GS} = 0V, I_D = 1mA$ $600$ $  V$ Zero gate voltage drain current $I_{DSS}$ $V_{DS} = 600V, V_{GS} = 0V$ $ 0.1$ $100$ $\mu A$ Gate - Source leakage current $I_{GSS}$ $V_{GS} = 10V, I_D = 1mA$ $2.5$ $ 4.5$ $V$ Gate threshold voltage $V_{GS(th)}$ $V_{DS} = 10V, I_D = 1mA$ $2.5$ $ 4.5$ $V$ Static drain - source on - state resistance $R_{DS(cn)}^{-4}$ $T_j = 25^{\circ}C$ $ 0.19$ $0.25$ $\Omega$	•Electrical characteristics (T <sub>a</sub> = 25°C)							
ImageMin.Typ.Max.Drain - Source breakdown voltage $V_{(BR)DSS}$ $V_{GS} = 0V, I_D = 1mA$ $600$ $  V$ Zero gate voltage drain current $I_{DSS}$ $T_j = 25^{\circ}C$ $ 0.1$ $100$ $\mu A$ Gate - Source leakage current $I_{GSS}$ $V_{GS} = \pm 30V, V_{DS} = 0V$ $  \pm 100$ $nA$ Gate threshold voltage $V_{GS(th)}$ $V_{DS} = 10V, I_D = 1mA$ $2.5$ $ 4.5$ $V$ Static drain - source on - state resistance $R_{DS(on)}^{*4}$ $T_j = 25^{\circ}C$ $ 0.19$ $0.25$ $\Omega$					Values			
voltage $V_{(BR)DSS}$ $V_{GS} = 0V, I_D = 1mA$ $600$ $  V$ Zero gate voltage drain current $I_{DSS}$ $T_j = 25^{\circ}C$ $ 0.1$ $100$ $\mu A$ $T_j = 125^{\circ}C$ $      -$ Gate - Source leakage current $I_{GSS}$ $V_{GS} = \pm 30V, V_{DS} = 0V$ $  \pm 100$ $nA$ Gate threshold voltage $V_{GS(th)}$ $V_{DS} = 10V, I_D = 1mA$ $2.5$ $ 4.5$ $V$ Static drain - source on - state resistance $R_{DS(on)}^{*4}$ $T_j = 25^{\circ}C$ $ 0.19$ $0.25$ $\Omega$ $T_j = 125^{\circ}C$ $ 0.37$ $ 0.37$ $ 0.37$ $-$	Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Drain - Source breakdown voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> = 0V, I <sub>D</sub> = 1mA	600	-	-	V	
Gate threshold voltage $V_{GS(th)}$ $V_{DS} = 10V, I_D = 1mA$ 2.5       -       4.5       V         Static drain - source on - state resistance $R_{DS(on)}^{*4}$ $T_j = 25^{\circ}C$ -       0.19       0.25 $\Omega$ $T_j = 125^{\circ}C$ -       0.37       -       0.37       -	Zero gate voltage drain current	I <sub>DSS</sub>	T <sub>j</sub> = 25°C	-	0.1	100	μA	
Static drain - source on - state resistance $V_{GS} = 10V, I_D = 10A$ -       0.19       0.25       Ω         T <sub>j</sub> = 125°C       -       0.37       -       0.37       -	Gate - Source leakage current	L <sub>GSS</sub>	$V_{GS}$ = ±30V, $V_{DS}$ = 0V	-	-	±100	nA	
Static drain - source on - state resistance $V_{GS} = 10V, I_D = 10A$ -       0.19       0.25       Ω         T <sub>j</sub> = 125°C       -       0.37       -       0.37       -	Gate threshold voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> = 10V, I <sub>D</sub> = 1mA	2.5	-	4.5	V	
Gate resistance $R_G$ f = 1MHz, open drain - 13.4 - $\Omega$	Static drain - source on - state resistance		T <sub>j</sub> = 25°C	-		0.25	Ω	
	Gate resistance	R <sub>G</sub>	f = 1MHz, open drain	-	13.4	-	Ω	



# Electrical characteristics (T<sub>a</sub> = 25°C)

Parameter Symbol Conditions		Conditions		Values		Unit			
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit			
Forward Transfer Admittance	Y <sub>fs</sub>  *4	V <sub>DS</sub> = 10V, I <sub>D</sub> = 10A	7	14	-	S			
Input capacitance	C <sub>iss</sub>	V <sub>GS</sub> = 0V	-	2040					
Output capacitance	C <sub>oss</sub>	V <sub>DS</sub> = 25V	-	1660		pF			
Reverse transfer capacitance	C <sub>rss</sub>	f = 1MHz	-	70	-				
Turn - on delay time	$t_{d(on)}^{*4}$	$V_{DD} \simeq 300$ V, $V_{GS}$ = 10V		40	-				
Rise time	t <sub>r</sub> *4	I <sub>D</sub> = 10A	6	60	-	20			
Turn - off delay time	t <sub>d(off)</sub> *4	$R_L \simeq 30\Omega$	-	230	-	ns			
Fall time	t <sub>f</sub> *4	R <sub>G</sub> = 10Ω	-	70	-				
•Gate charge characteristics									

# • Gate charge characteristics ( $T_a = 25^{\circ}C$ )

Parameter	Symbol	Conditions		Values		Unit
Farameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Total gate charge	Q <sub>g</sub> *4	V <sub>DD</sub> ≃ 300V	-	65	-	
Gate - Source charge	Q <sub>gs</sub> *4	I <sub>D</sub> = 20A	-	10	-	nC
Gate - Drain charge	Q <sub>gd</sub> *4	V <sub>GS</sub> = 10V	-	25	-	
Gate plateau voltage	V <sub>(plateau)</sub>	$V_{DD} \simeq 300V$ , $I_D = 20A$	-	5.9	-	V

\*1 Limited only by maximum temperature allowed.

\*2 Pw≤10µs, Duty cycle≤1%

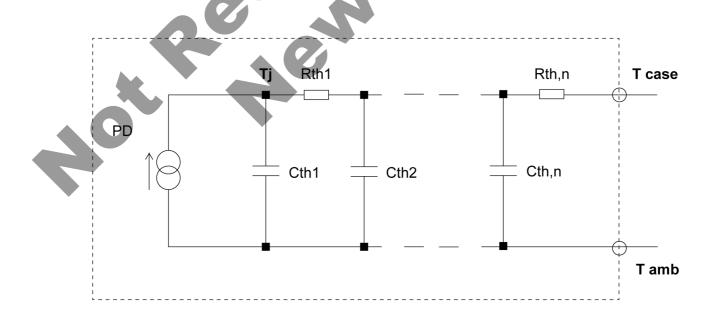
\*3 L~500 $\mu$ H, V<sub>DD</sub>=50V, R<sub>G</sub>=25 $\Omega$ , starting T<sub>j</sub>=25°C

\*4 Pulsed

# Body diode electrical characteristics (Source-Drain) (T<sub>a</sub> = 25°C)

Deremeter	Cumph of	Conditions	Values			Linit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Continuous forward current	۱ <sub>S</sub> *1	T - 25°0	-	-	20	А
Pulse forward current	ا <sub>SP</sub> *2	T <sub>C</sub> = 25°C	-	-	80	A
Forward voltage	$V_{SD}^{*4}$	V <sub>GS</sub> = 0V, I <sub>S</sub> = 20A	-	-	1.5	V
Reverse recovery time	t <sub>rr</sub> *4		-	493	-	ns
Reverse recovery charge	Q <sub>rr</sub> *4	I <sub>S</sub> = 20A di/dt = 100A/μs		7.43	-	μC
Peak reverse recovery current	۲ <sub>rrm</sub> *4			30.2	-	А

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ak reverse reco	very current	I <sub>rrm</sub> *4			30.2	-	А
Typical transie	nt thermal ch	aracteristics			19		
Symbol	Value	Unit	Sym	bol	Value		Unit
R <sub>th1</sub>	0.0462		Ctt	11	0.00308	8	
R <sub>th2</sub>	0.17	K/W	Ct	12	0.0118		Ws/K





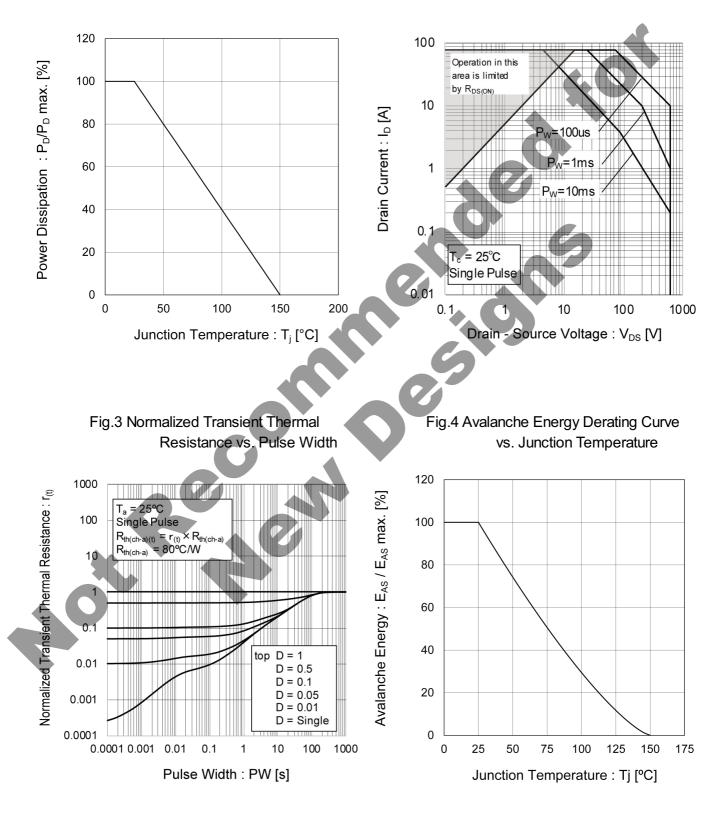
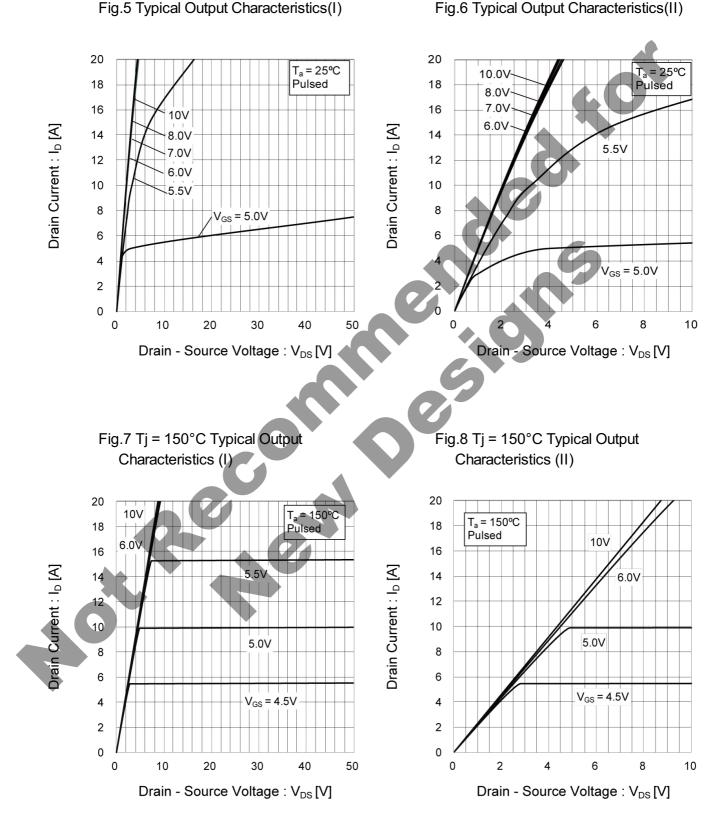


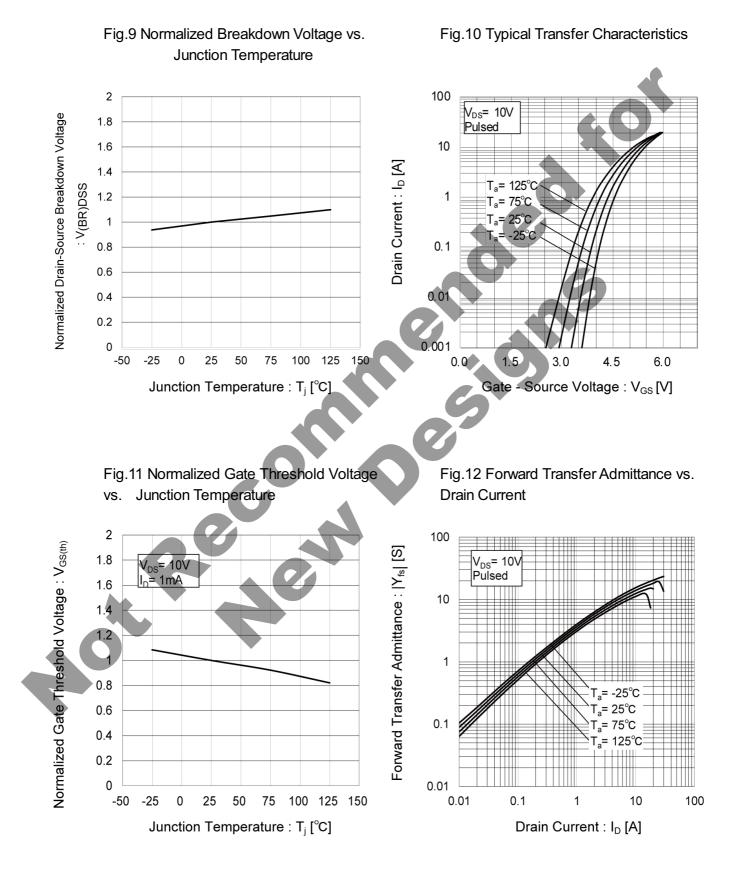
Fig.1 Power Dissipation Derating Curve

Fig.2 Maximum Safe Operating Area











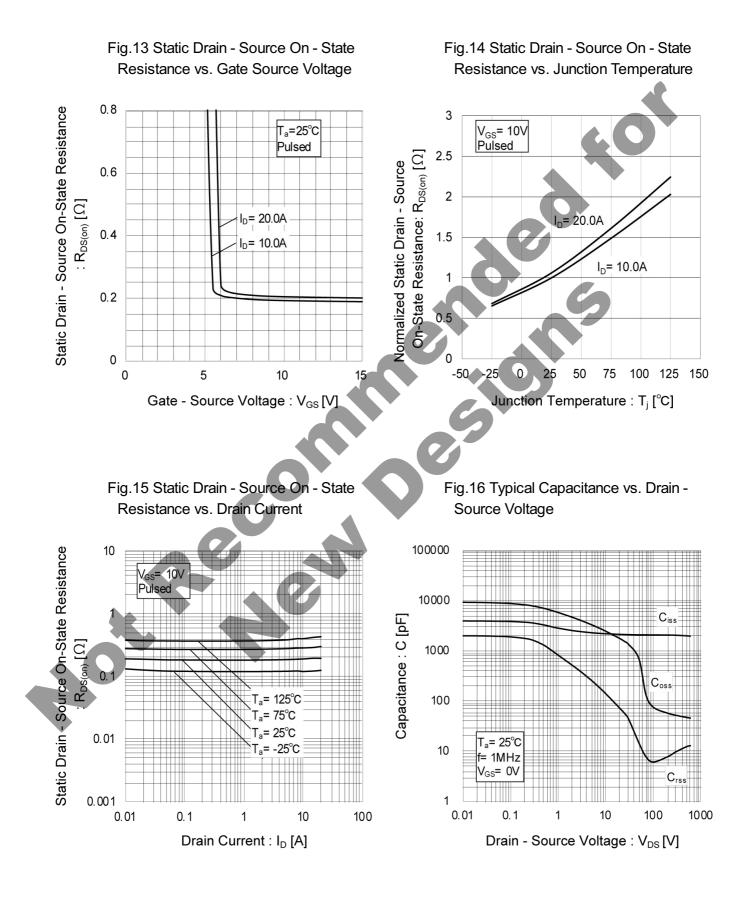
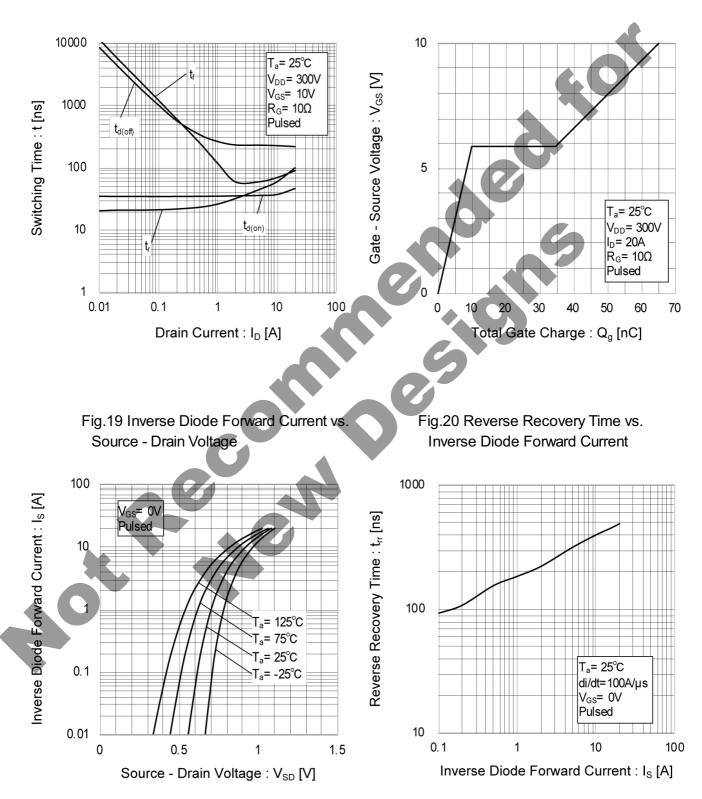
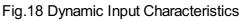




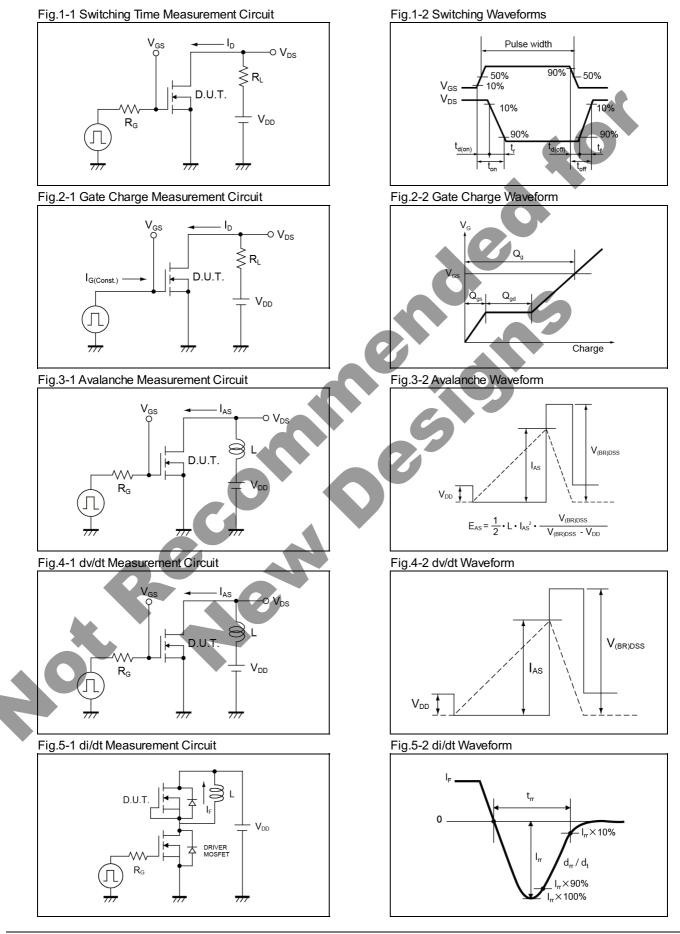
Fig.17 Switching Characteristics







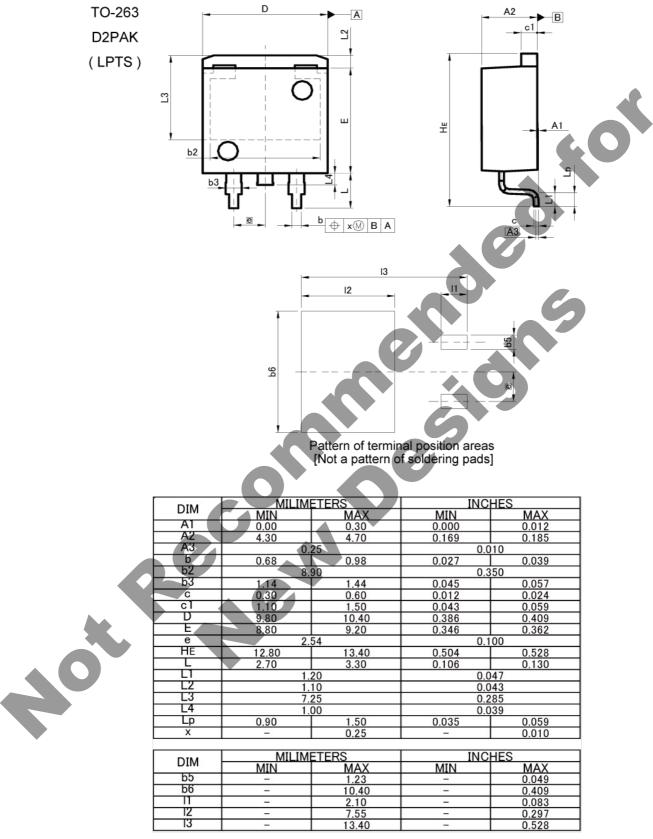
## Measurement circuits



10/11



## Dimensions



Dimension in mm/inches



# Notice

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1. Our Products are designed and manufactured for application in ordinary electronic equipments (such as AV equipment, OA equipment, telecommunication equipment, home electronic appliances, amusement equipment, etc.). If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment <sup>(Note 1)</sup>, transport equipment, traffic equipment, aircraft/spacecraft, nuclear power controllers, fuel controllers, car equipment including car accessories, safety devices, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

(Note1) Medical E	quipment Classifi	cation of the Spec	ific Applications
JAPAN	USA	EU	CHINA

JAPAN	USA	EU	CHINA
CLASSⅢ		CLASS II b	CLASSI
CLASSⅣ	CLASSII	CLASSⅢ	CLASSI

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  - [a] Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
  - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
  - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
  - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
  - [f] Sealing or coating our Products with resin or other coating materials
  - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power, exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.

De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.

- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

#### Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

#### Precautions Regarding Application Examples and External Circuits

- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
- 2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

#### **Precaution for Electrostatic**

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

#### Precaution for Storage / Transportation

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
  - [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

#### **Precaution for Product Label**

A two-dimensional barcode printed on ROHM Products label is for ROHM's internal use only.

#### **Precaution for Disposition**

When disposing Products please dispose them properly using an authorized industry waste company.

#### Precaution for Foreign Exchange and Foreign Trade act

Since concerned goods might be fallen under listed items of export control prescribed by Foreign exchange and Foreign trade act, please consult with ROHM in case of export.

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